NSN 5962-01-051-8516

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-051-8516

Body Length:
0.440 inches
Body Width:
Between 0.245 inches and 0.285 inches
Body Height:
Between 0.045 inches and 0.085 inches
Maximum Power Dissipation Rating:
473.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Receiving set, radar type an/apr-38
Features Provided:
Hermetically sealed and monolithic and positive outputs and w/enable and asynchronous and resettable and synchronous and
complementary outputs
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Flat pack
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
9 input
Case Outline Source And Designator:
F-5 mil-m-38510
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Memory Device Type:
Rom
Memory Capacity:
Unknown
Test Data Document:
81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:

Shelf Life:

NI/o

16 flat leads

Specification Data:

81349-mil-m-38510/159 government specification

NSN 5962-01-051-8516

Memory Microcircuit - Page 2 of 2



Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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